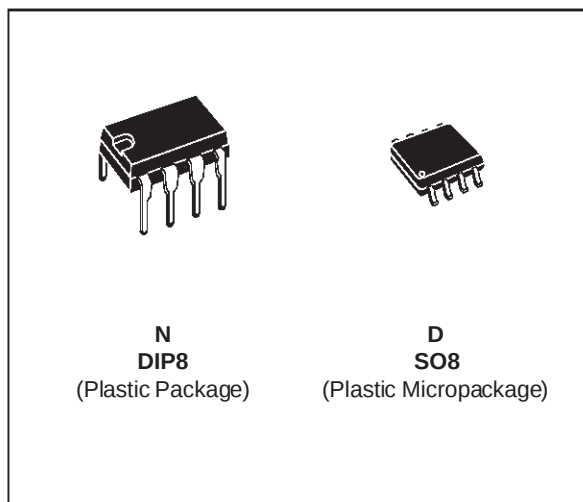




TEB1033 TEF1033-TEC1033

PRECISION DUAL OPERATIONAL AMPLIFIERS

- VERY LOW INPUT OFFSET VOLTAGE : 1mV max.
- LOW DISTORTION RATIO
- LOW NOISE
- VERY LOW SUPPLY CURRENT
- LOW INPUT OFFSET CURRENT
- LARGE COMMON-MODE RANGE
- HIGH OUTPUT CURRENT
- GAIN-BANDWIDTH PRODUCT : 2MHz
- TEMPERATURE DRIFT : $2\mu\text{V}/^\circ\text{C}$
- LONG TERM STABILITY : $8\mu\text{V}/\text{YEAR}$ (for $T_{\text{amb}} \leq 50^\circ\text{C}$)



DESCRIPTION

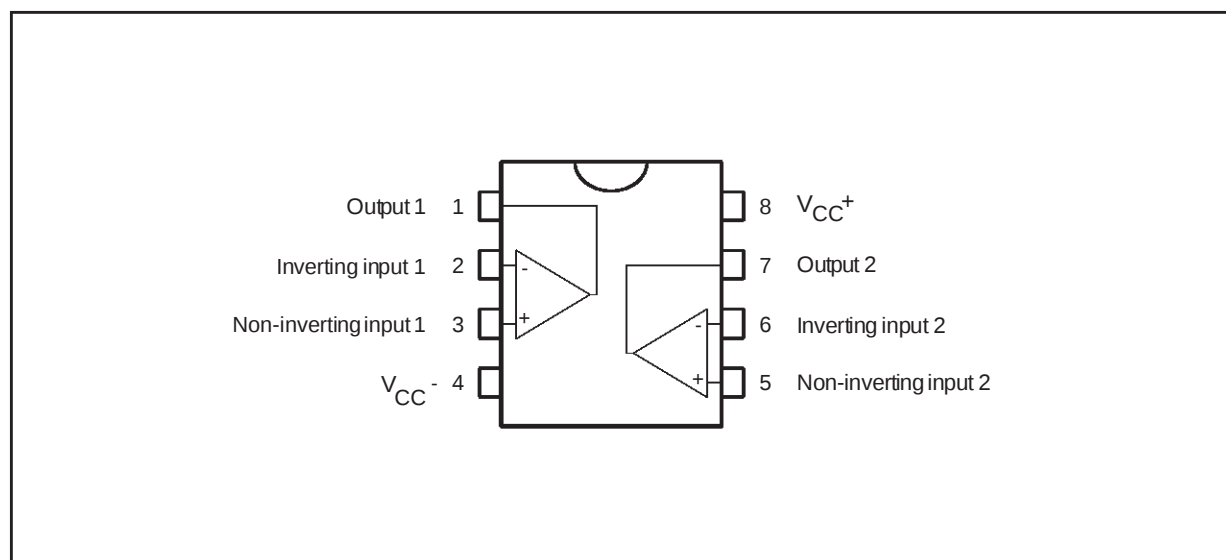
The TEB1033, TEF1033 and TEC1033 are high performance dual-operational amplifiers intended for active filter applications. The internal phase compensation allows stable operation as voltage follower in spite of their high gain-bandwidth product. The circuits present very stable electrical characteristics over the entire supply voltage range.

ORDER CODES

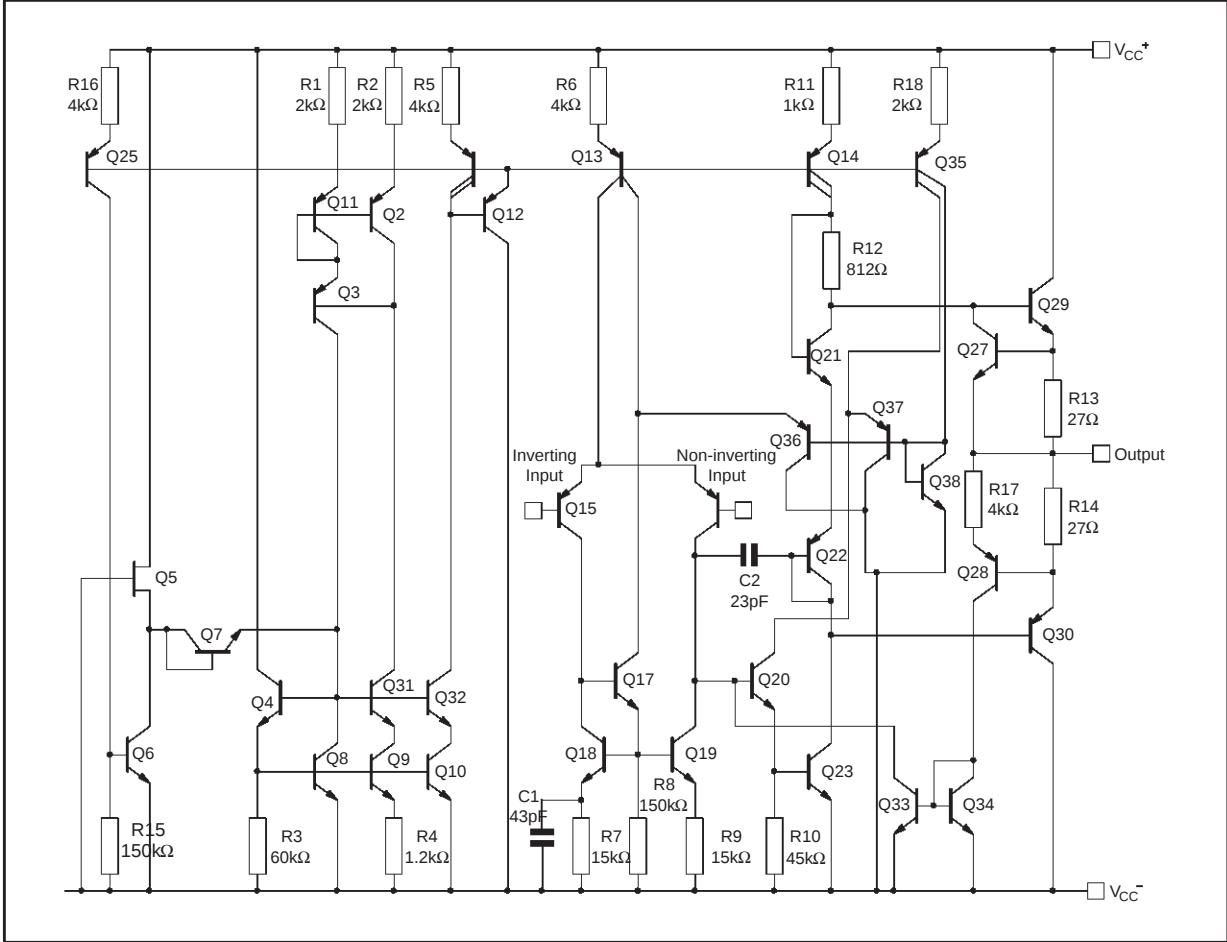
Part Number	Temperature Range	Package	
		N	D
TEB1033	$0^\circ\text{C}, +70^\circ\text{C}$	•	•
TEF1033	$-40^\circ\text{C}, +105^\circ\text{C}$	•	•
TEC1033	$-55^\circ\text{C}, +125^\circ\text{C}$	•	•

Example : TEB1033N

PIN CONNECTIONS (top view)



BLOCK DIAGRAM (1/4 TEB1033)



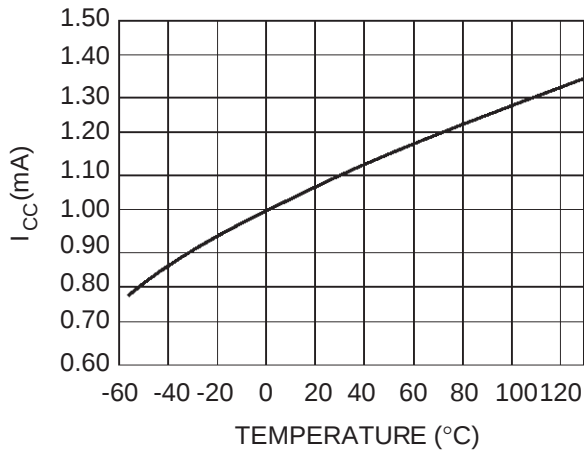
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage		± 18	V
V _i	Input Voltage		± V _{CC}	V
V _{id}	Differential Input Voltage		± (V _{CC} - 1)	V
P _{tot}	Power Dissipation	D suffix N suffix	400 665	mW
T _{oper}	Operating Free-air Temperature Range	TEB1033 TEF1033 TEC1033	0 to +70 -40 to +105 -55 to +125	°C
T _{stg}	Storage Temperature Range		-65 to +150	°C

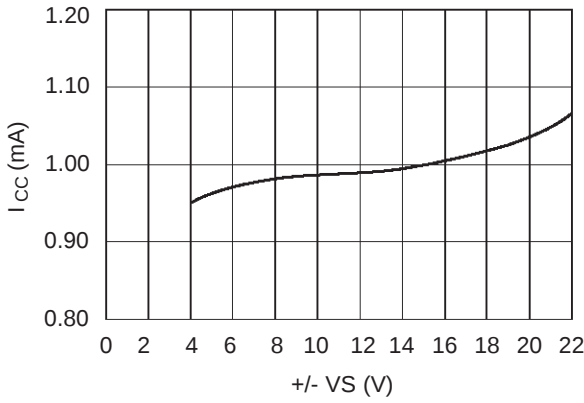
ELECTRICAL CHARACTERISTICS $V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	TEB 1033 TEF 1033 TEC 1033			Unit
		Min.	Typ.	Max.	
V_{io}	Input Offset Voltage ($R_S \leq 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		0.3	1 3	mV
DV_{io}	Input Offset Voltage Drift		2		$\mu V/^{\circ}C$
I_{io}	Input Offset Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 40	nA
I_{ib}	Input Bias Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		50	100 200	nA
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega$, $V_O = \pm 10V$) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 40	120		V/mV
SVR	Supply Voltage Rejection Ratio (DV_{CC} from $\pm 15V$ to $\pm 4V$) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 70	100		dB
I_{CC}	Supply Current, all Amp, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	1.5 2	mA
V_{icm}	Input Common Mode Voltage Range $T_{amb} = 25^{\circ}C$	± 12			V
CMR	Common Mode Rejection Ratio ($R_S \leq 10k\Omega$, $V_I = \pm 10V$) $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 70	100		dB
I_{os}	Output Short-circuit Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	10 10	23	40 40	mA
$\pm V_{opp}$	Output Voltage Swing $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $V_{CC} = \pm 4V$, $R_L = 2k\Omega$, $T_{amb} = 25^{\circ}C$ $V_{CC} = \pm 6V$, $R_L = 600\Omega$, $T_{amb} = 25^{\circ}C$	13 12 2.8 4.6	14 3		V
SR	Slew-rate ($V_I = \pm 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain)	0.6	1		V/ μs
GBP	Gain Bandwidth Product ($f = 100kHz$, $T_{amb} = 25^{\circ}C$, $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$)	1.5	2		MHz
R_i	Input Resistance		1		M Ω
THD	Total Harmonic Distortion ($f = 1kHz$, $A_v = 20dB$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, $V_o = 2V_{pp}$)		0.008	0.05	%
e_n	Equivalent Input Noise Voltage ($f = 1kHz$) $R_S = 50\Omega$ $R_S = 1k\Omega$ $R_S = 10k\Omega$		8 10 18	15	$\frac{nV}{\sqrt{Hz}}$
V_{OPP}	Large Signal Voltage Swing $R_L = 10k\Omega$, $f = 10kHz$	26	28		V
ϕ_m	Phase Margin		45		Degrees
V_{01}/V_{02}	Channel Separation	100	120		dB

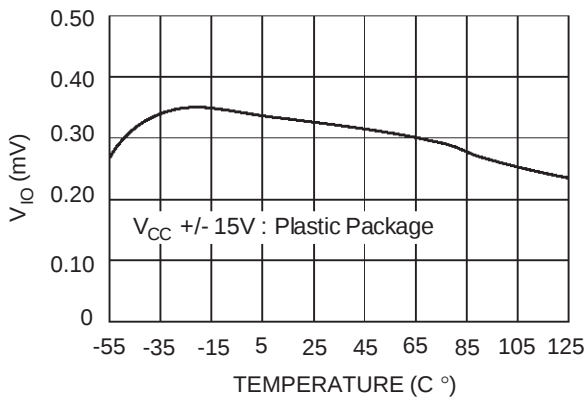
SUPPLY CURRENT VERSUS AMBIENT TEMPERATURE



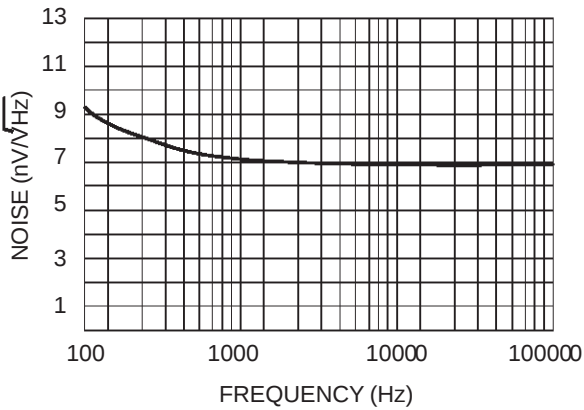
SUPPLY CURRENT VERSUS SUPPLY VOLTAGE



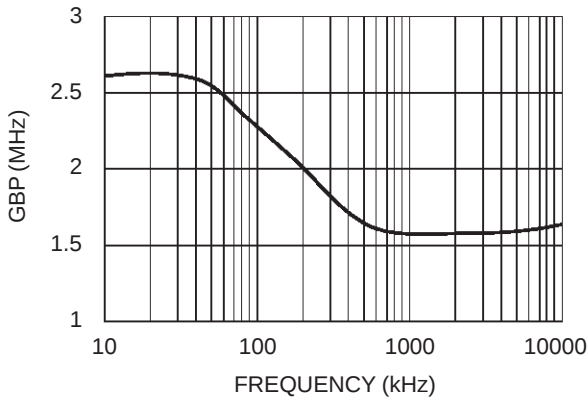
OFFSET VOLTAGE VERSUS AMBIENT TEMPERATURE



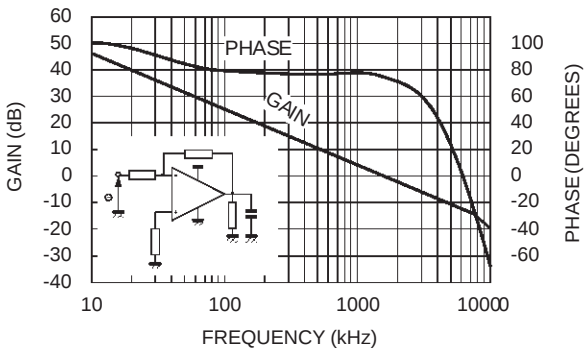
TOTAL INPUT NOISE VERSUS FREQUENCY



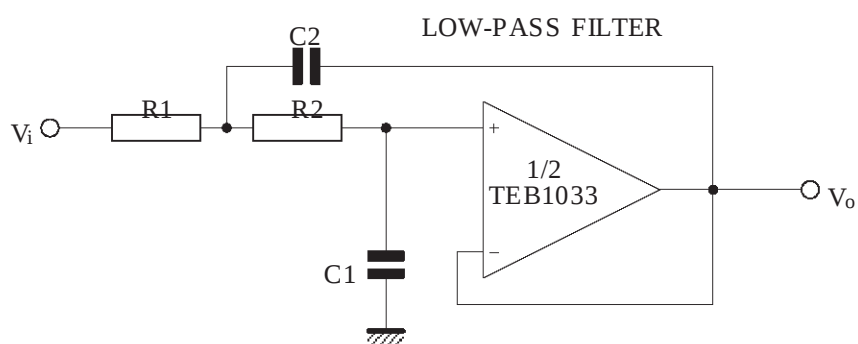
GAIN BANDWIDTH PRODUCT VERSUS FREQUENCY



ODE PLOT



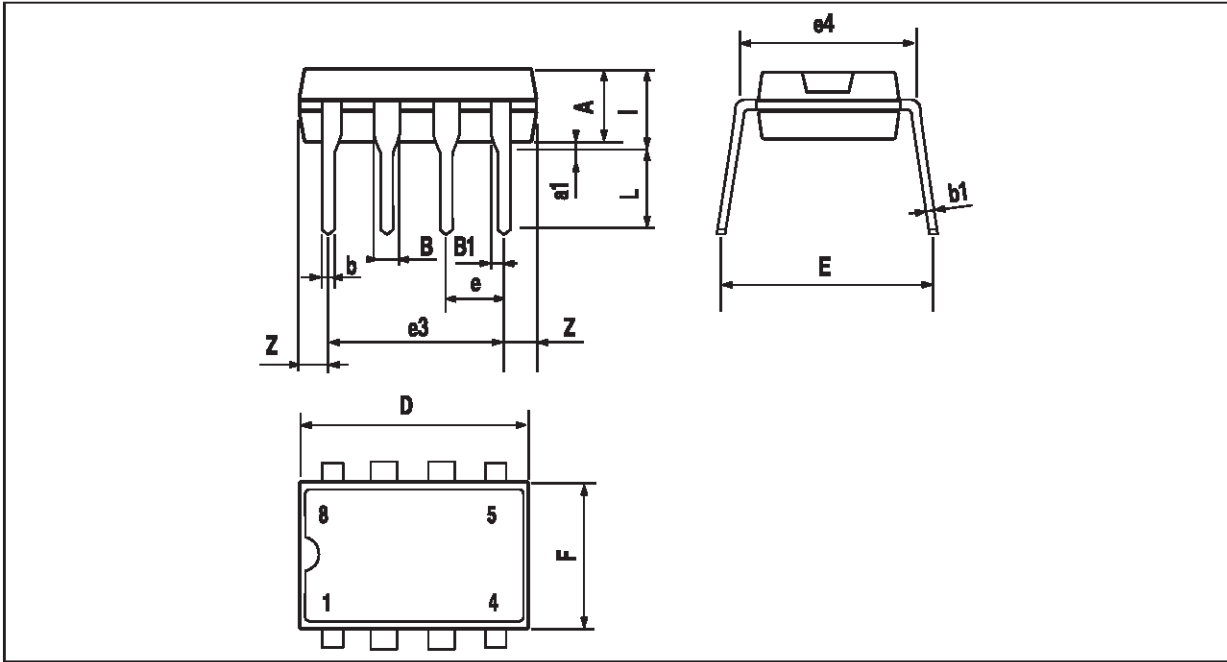
TYPICAL APPLICATION



$$\frac{V_o}{V_i} = \frac{1}{1 + 2\xi \frac{S}{\omega_c} + \frac{S^2}{\omega_c^2}}$$

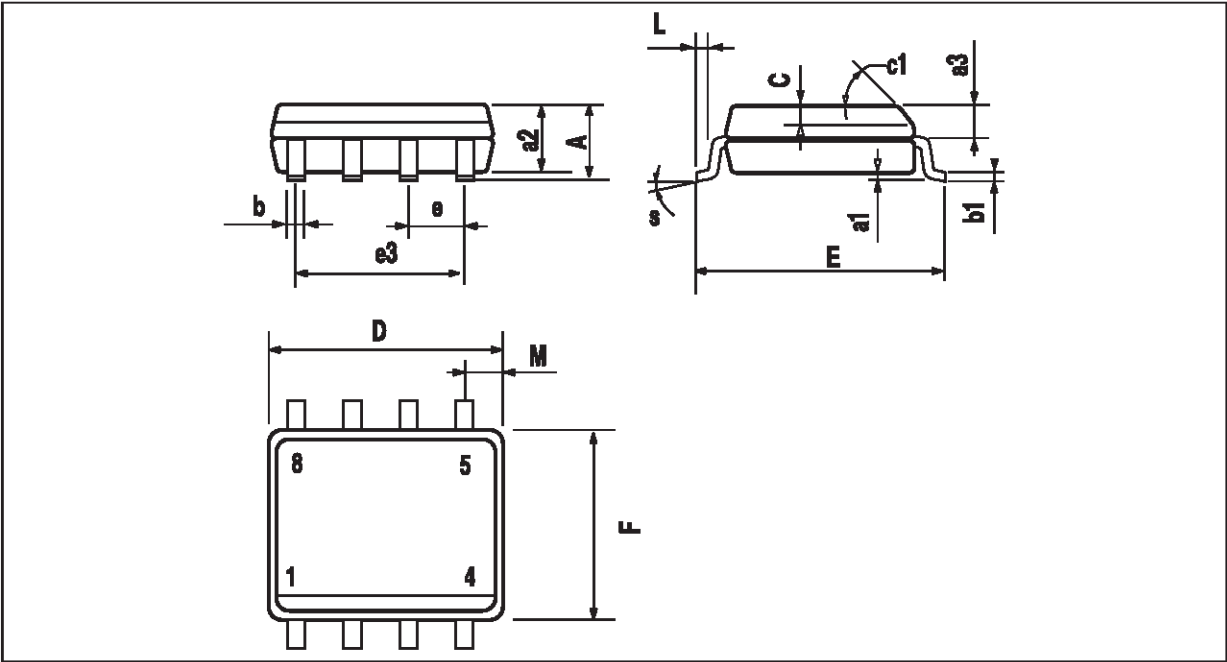
$\omega_c = 2\pi f_c$, with f_c = cut-off frequency
 ξ = damping factor

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

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